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ADC12EU050

Ultra-Low Power, Octal, 12-bit, 40-50 MSPS Sigma-Delta **Analog-to-Digital Converter**

General Description

The ADC12EU050 is a 12-bit, ultra-low power, octal A/D converter for use in high performance analog to digital applications. The ADC12EU050 uses an innovative continuous time sigma delta architecture offering ultra low power consumption and an alias free sample bandwidth up to 25MHz. The input stage of each channel features a proprietary system to ensure instantaneous recovery from overdrive. Instant overload recovery (IOR) with no memory effect guarantees the elimination of phase errors resulting from out of range input signals. The ADC12EU050 reduces interconnection complexity by using programmable serialized outputs which offer the industry standard LVDS and SLVS modes. Power consumption of only 48mW per channel @ 50MSPS gives a total chip power consumption of 384mW. The ADC12EU050 can operate entirely from a 1.2V supply, although a separate output driver supply of up to 1.8V can be used. The device operates from -40 to +85 °C and is supplied in a 10 x 10 mm², 68 pin package.

Features

- Xignal™ CT∑Δ ADC technology
- 40-50MSPS sampling rate
- Anti-alias filter free Nyquist sample range
- Unique Instant Overload Recovery (IOR)
- Wide 2.10 V_{PP} input range
- 1.2V supply voltage
- Integrated precision LC PLL
- Serial control via SPI compatible interface

Key Specifications

Resolution 12 Bits

40 to 50 MSPS Conversion Rate SNR

69.3 dBFS (typ) @ 50 MSPS

 $f_{IN} = 4.4MHz$

-76.6 dB (typ) @ 50 MSPS

ADC12EU050 Ultra-Low Power, Octal, 12-bit, 40-50 MSPS Sigma-Delta Analog-to-Digital

 $f_{IN} = 4.4MHz$ Per Channel Power 48 mW/ch (typ) @ 50MSPS

Total Active Power 385 mW (typ) @ 50MSPS

 $>110 \text{ dB } @ f_{IN} = 4.4 \text{MHz}$ Inter-Channel Isolation

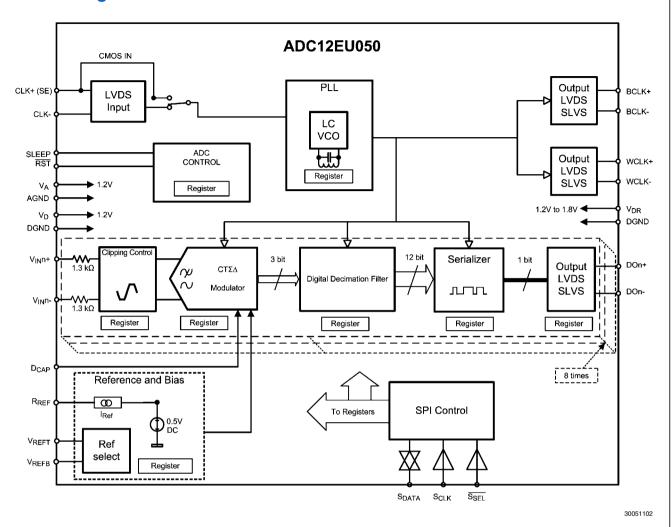
Operating Temp. Range -40 to +85 °C

Applications

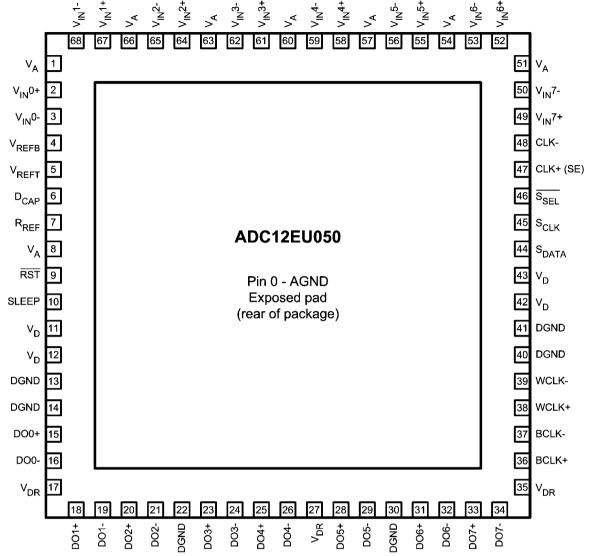
THD

- Medical imaging, ultrasound
- Industrial ultrasound, such as non-destructive testing
- Communications
- Battery powered portable systems

Block Diagram



Connection Diagram



30051101

Ordering Information

Industrial (–40°C ≤ T _A ≤ +85°C)	Package
ADC12EU050CIPLQ	68 Pin LLP
ADC12EU050EB	Evaluation Board

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Pin Descriptions

Pin No.	Name	Туре	Function and Connection
ANALOG I/O			
_	V _{IN} 0+		
2	V _{IN} 0-		
3	V _{IN} 1+		
67	V _{IN} 1-		
68	V _{IN} 2+		
64	V _{IN} 2-		
65	V _{IN} 2+		Differential analysis involve to the ADC for shannels 0 to 7. The
61	 		Differential analog inputs to the ADC, for channels 0 to 7. The
62	V _{IN} 3-	Input	negative input pin may be connected via a capacitor to AGND or
58	V _{IN} 4+		the inputs may be transformer coupled for single ended operation
59	V _{IN} 4-		Differential inputs are recommended for best performance.
55	V _{IN} 5+		
56 52	V _{IN} 5-		
	V _{IN} 6+		
53 49	V _{IN} 6-		
50	V _{IN} 7+		
50	V _{IN} 7-		
4	V		Optional negative reference voltage to improve multi-channel ADO
4	V _{REFB}		matching. This pin must be connected to AGND.
5	V_{REFT}		Optional positive reference voltage to improve multi-channel ADC matching. If using the internal reference, this pin should be left tied to AGND through a 100nF capacitor. If using an external reference voltage, this pin should be connected to the positive reference voltage, which must lie in the range specified in the Electrical Characteristics table.
6	D _{CAP}	Input	This pin provides the capacitance for the low pass filter in the modulator's DAC. It must be connected to AGND through a minimum 100nF capacitor. It is possible to decrease the noise close to the carrier by increasing this capacitor, up to a maximum of 10µF. See Applications Information for further information on the selection of this capacitor.
7	R _{REF}	Input/Output	External bias reference resistor. This pin must always be connected to AGND through a resistor, whether the internal reference or an external reference voltage is used. The resistor value must be $10k\Omega \pm 1\%$.
DIGITAL I/O			
9	RST	Input	This pin is an active low reset for the entire ADC, both analog and digital components. The pin must be held low for 500ns then returned to high in order to ensure that the chip is reset correctly.
10	SLEEP	Input	Sleep mode. Toggling this pin to high will cause the ADC to ente the low power sleep mode. When the pin is returned to low, the chip will, after the specified time to exit sleep mode, return to normal operation.

Pin No.	Name	Туре	Function and Connection
15	DO0+	-76-	
16	DO0-		
18	DO1+		
19	DO1-		
20	DO2+		Differential Serial Outputs for channels 0 to 7. Each pair of outputs
21	DO2-		provides the serial output for the specific channel. The default
23	DO2+		output is reduced common mode LVDS format, but by
24	DO3-		programming the appropriate control registers, the output format
25	DO3- DO4+	Output	can be changed to SLVS or LVDS.
26	DO4-		By programming TX_term (bit 4) in the LVDS Control register, it is
28	DO5+		possible to internally terminate these outputs with 100 ohm
29	DO5-		resistors.
31	DO5- DO6+		resisions.
31 32	DO6-		
33	DO7+		
34	DO7-		
			Bit clock. Differential output clock used for sampling the serial
			outputs. Information on timing can be seen in the Electrical
36	BCLK+	Output	Specifications section of the datasheet.
37	BCLK-	o asp as	By programming TX_term (bit 4) in the LVDS Control register, it is
			possible to internally terminate these outputs with 100 ohm
			resistors.
			Word Clock. Differential output frame clock. Information on timing
			can be seen in the Electrical Specifications section of the
38	WCLK+	Output	datasheet.
39	WCLK-	Output	By programming TX_term (bit 4) in the LVDS Control register, it is
			possible to internally terminate these outputs with 100 ohm
			resistors.
			SPI data input and output. This pin is used to send and receive SPI
44	S _{DATA}	Input/Output	address and data information. The direction of the pin is controlled
			internally by the ADC based on the SPI protocol.
			SPI clock. In order to use the SPI interface, a clock must be
45	S _{CLK}	Input	provided on this pin. See Electrical Specifications for SPI clock and
		•	timing information.
			SPI chip select. This active low pin is used to enable the serial
46	S _{SEL}	Input	interface.
			Differential Input Clock. The input clock must lie in the range of
47	CLK+ (SE)		40MHz to 50MHz. It is used by the PLL to generate the internal
48	CLK-	Input	sampling clocks. A single ended clock can also be used, and
			should be connected to pin 47.
POWER SUPI	PLY		· · · · · · · · · · · · · · · · · · ·
1, 8, 51, 54,			Analog Power Supply. All pins should be connected to the same
57, 60, 63, 66	V _A	Power	1.2V supply, with voltage limits as in the Electrical Specification.
0	AGND	Ground	Analog Ground Return.
	, (0145	Giodila	Digital Power Supply. Connect to 1.2V, with voltage limits as in the
11, 12, 42, 43	V_D	Power	Electrical Specification.
13, 14, 22,	D0112	0 '	·
30, 40, 41	DGND	Ground	Digital and Output Driver Ground Return.
			Output Driver Power Supply. Can be connected to 1.2V – 1.8V,
		_	I I
17, 27, 35	V_{DR}	Power	depending on application requirements. Voltage limits are described in more detail in the Electrical Specification.

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Absolute Maximum Ratings (Note 1, Note

3)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V _A , V _D)	-0.3V to 1.4V
IO Supply Voltage (V _{DR})	-0.3 to 2.0V
Voltage at Analog Inputs	-0.3 to 1.4V
Voltage at SPI Inputs	-0.3 to 2.5V
Input Current, V _{IN} +, V _{IN} -	±1mA
Input Current, other pins	±10mA
ESD Susceptibility	
Human Body Model	2000V
Machine Model	200V
Charged Device Mode	1,000V
Soldering Temperature	
Infrared, 10 seconds	235°C

Storage Temperature Range -65°C to +125°C Soldering process must comply with National Semiconductor's Reflow Temperature Profile specifications. Refer to www.national.com/packaging.

Operating Ratings (Note 2, Note 3)

9 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	_, ,
Operating Temperature Range	-40°C to +85°C
Supply Voltage (V _A =V _D)	+1.14 to +1.26V
IO Supply Voltage (V _{DR})	+1.14 to +1.89V
Minimum rise time on V_A , V_D ,	40µs
V _{DR} at power-up	
Analog Inputs (V _{IN} N+, V _{IN} N-)	-0.10 to V _A
SPI Inputs (S_{DATA} , S_{SEL} , S_{CLK})	+1.14 to +2.50V
V _{REFT} (When using external reference)	475mV to 525mV
V_{REFB}	AGND
V _{CM} Input Common Mode Range (Differential Input)	0.4V to 1.2V
Ground Difference IAGND- DGNDI	<50mV

Electrical Characteristics

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm $\pm 1\%$; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 5$ 0MHz; $f_S = 5$ 0MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symbol	Parameter	Conditions	Typical (Note 4)	Limits	Units
Static Co	onverter Characteristics	•	!		
	Resolution (No missing codes guaranteed)			12	Bits
INL	Integral Non Linearity		±0.75	±3.0	LSB
DNL	Differential Non Linearity		±0.35	±0.75	LSB
PSE	Positive Full Scale Error		±0.66	±3	%FS
NSE	Negative Full Scale Error		±0.58	±3	%FS
GE	Gain Error		±1.23		%FS
Dynamic	Converter Characteristics – Instant	Overload Recovery (IOR) Off			
		$f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	69.3	67.0	dBFS (min)
OND	Signal to Noise Ratio(Note 5)	$f_{CLK} = 50MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	69.0		dBFS
SNR		$f_{CLK} = 40MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	69.9		dBFS
		$f_{CLK} = 40MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	69.6		dBFS
	Signal to Noise and Distortion(Note 5)	$f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	68.5	62.5	dBFS (min)
011145		$f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	68.5		dBFS
SINAD		$f_{CLK} = 40MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	69.3		dBFS
		$f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	69.2		dBFS
		$f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	11.1	10.1	Bits (min)
		$f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	11.1		Bits
ENOB	Effective Number of Bits	$f_{CLK} = 40MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	11.2		Bits
		$f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	11.2		Bits
		f _{CLK} = 50MHz, f _{IN} = 4.4MHz, V _{IN} = -0.5dBFS	-76	-65	dBc (max)
		$f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	-78		dBc
THD	Total Harmonic Distortion	$f_{CLK} = 40MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	-77		dBc
		$f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	-79		dBc

	•			
	$f_{CLK} = 50MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	-81	-66	dBc (max)
Casand Harmania Distantian	$f_{CLK} = 50MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	-79		dBc
Second Harmonic Distortion	$f_{CLK} = 40MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	-82		dBc
	$f_{CLK} = 40MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	-80		dBc
	f_{CLK} = 40MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS	dBc (max)		
Third Hower onic Distantion	$f_{CLK} = 50MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	-97		dBc
Third Harmonic Distortion	$f_{CLK} = 40MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	-84		dBc
	$f_{CLK} = 40MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	-108		dBc
	$f_{CLK} = 50MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	77	66	dBc (min)
	$f_{CLK} = 50MHz$, $f_{IN} = 9.5MHz$, $V_{IN} = -0.5dBFS$	78		dBc
Spurious Free Dynamic Hange	$f_{CLK} = 40MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	78		dBc
	$f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	79		dBc
	f ₁ = 9.6MHz, V _{IN} = -6dBFS	70		IDEO
Intermodulation Distortion	f ₂ = 10.1MHz, V _{IN} = -6dBFS	-70		dBFS
Converter Characteristics – Instant	Overload Recovery (IOR) On			
	$f_{CLK} = 50MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	67.6	65.5	dBFS (min)
0: 1: N: D: (A) (5)	$f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	67.4		dBFS
Signal-to-Noise Ratio(Note 5)	$f_{CLK} = 40MHz$, $f_{IN} = 4.4MHz$, $V_{IN} = -0.5dBFS$	68.4		dBFS
	$f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	68.2	61.5	dBFS
Signal-to-Noise and Distortion(Note 5)	$f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS$	67.0	61.5	dBFS (min
	$f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS$	67.0		dBFS
		67.9		dBFS
		67.8	7.8	dBFS
		10.8	9.9	Bits (min)
		10.8		Bits
Effective Number of Bits		11.0		Bits
		11.0		Bits
		-76	-64	dBc (max)
	<u> </u>			dBc
Total Harmonic Disortion		-77		dBc
				dBc
			-65	dBc (max)
				dBc
Second Harmonic Distortion				dBc
				dBc
			-67	dBc (max)
			, , , , , , , , , , , , , , , , , , , 	dBc (max)
Third Harmonic Distortion				dBc
				dBc
		-	65	dBc (min)
		-	00	dBc (IIIII)
Spurious Free Dynamic Range				dBc
				dBc
		/ 0		UDC
Intermodulation Distortion	1	-70		dBFS
	Signal-to-Noise Ratio(Note 5) Signal-to-Noise and Distortion(Note 5) Effective Number of Bits Total Harmonic Disortion Second Harmonic Distortion Third Harmonic Distortion Spurious Free Dynamic Range	Third Harmonic Distortion	Third Harmonic Distortion f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -97 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -97 f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -84 f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -84 f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 60MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -78 f_{CLK} = 40MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 4.4MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz, V_{IN} = -0.5dBFS -70 f_{CLK} = 50MHz, f_{IN} = 9.5MHz,	Third Harmonic Distortion

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Symbol	Parameter	Conditions	Typical (Note 4)	Limits	Units
Inter-cha	annel Characteristics				
	Channel to channel gain match		±0.1	±0.5	dB
	Inter-channel Isolation	f _{IN} = 4.4MHz @ -0.1dBFS Adjacent channel terminated	110		dB
Reference	ce And Analog Input Characteristics	s			
		IOR mode off	2.10	T	V _{PP}
V_{IN}	Full Scale Analog Input Voltage	IOR mode on	1.56		V _{PP}
	Maximum Input for Instantaneous Recovery from Overload	IOR mode on, f _{IN} < 12MHz	†	2.75	V _{PP} (max)
R _{IN}	Differential Input Impedance		2.61	2.4 2.8	$k\Omega$ (min) $k\Omega$ (max)
V _{CM}	Internal Input Common Mode	Generated internally	605	574 637	mV (min) mv (max)
	Input Impedance of V _{Reft}		20		kΩ
V _{REFOUT}	Internal Reference Voltage	Generated internally	502	480 520	mV (min) mV (max)
Power C	Characteristics		!		
I _A	Analog Supply Current	f _{CLK} = 50 MHz	152	163	mA (max)
I _D	Digital Supply Current	f _{CLK} = 50 MHz	130	147	mA (max)
I _{DR}	Output Driver Supply Current	LVDS, $V_{DR} = 1.8V$, $f_{CLK} = 50 \text{ MHz}$	38	45	mA (max)
		f _{CLK} = 50 MHz, Equalizer off	385	412	mW (max)
ŀ		f _{CLK} = 50 MHz, Equalizer on	435	470	mW (max)
I	Power consumption	f _{CLK} = 40 MHz, Equalizer off	343		mW
ŀ	Power consumption	f _{CLK} = 40 MHz, Equalizer on	383		mW
I		Sleep	40	50	mW (max)
		Power Down	5	15	mW (max)
	Per channel newer consumption	f _{CLK} = 50 MHz, Equalizer off	48	Γ	mW
	Per channel power consumption	f _{CLK} = 40 MHz, Equalizer off	43		mW
PSRR	Power supply rejection ratio	100mV, 100kHz to 1MHz sinusoid on $V_{\rm A}$	65		dB
CMRR	Common mode rejection ratio	100mV, 1MHz sinusoid on $V_{\rm IN}^+$ and $V_{\rm IN}^-$	60		dB
	Recovery time from sleep			12	μs (max)
	Recovery time from power down			18	ms (max)
	Recovery time from single channel power down			6	μs (max)

Digital Decimation Filter Characteristics

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm $\pm 1\%$; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 50$ MHz; $f_S = 50$ MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symbol	Parameter	Conditions(Note 6)	Typical (Note 4)	Limits	Units
	Pass Band	f _{CLK} = 50MHz	22		MHz
		f _{CLK} = 40MHz	17.6		MHz
	Pass Band Transition	f _{CLK} = 50MHz, -3dB attenuation	25		MHz
		f _{CLK} = 40MHz, -3dB attenuation	20		MHz
	Pass Band Ripple	f _{IN} < 22MHz		±0.01	dB
	Stop Band Begin	f _{CLK} = 50MHz	34.5		MHz
		f _{CLK} = 40MHz	27.6		MHz
	Stop Band Attenuation			72	dB (min)
	Group Delay Ripple (peak to peak)	f _{IN} < 22MHz, Equalizer on		0.05	Samples (max)

External Input Clock and PLL Characteristics

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm $\pm 1\%$; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 50$ MHz; $f_S = 50$ MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symbol	Parameter	Conditions	Typical (Note 4)	Limits	Units
External	Input Clock				
f _{CLK}	Allowed input clock frequency			40 50	MHz (min) MHz (max)
t _{CLK}	Allowed input clock period		1/f _{CLK}		ns
f _{CLK} DC	Allowed input clock duty cycle		50	20 80	% (min) % (max)
t _{JIN}	Allowed RMS clock jitter on input clock. (Note 9)	Integrated from 10Hz to BW _{loop}	300		fs rms
V _{CMCLK}	Allowed input clock common mode	(Note 8)		400 VDR	mV (min) mV (max)
	Allowed input clock voltage swing	Differential clock input.(Note 8)		200	mV peak-peak (min)
V _{ICLK}	Allowed Input clock voltage swing	Differential clock input.(Note 6)	400	VDR	mV peak-peak (max)
PLL					
f∑∆	Over-sampling frequency			640 800	MHz (min) MHz (max)
DW	DLL Loop filter bendwidth	Low Bandwidth	400		kHz
BW _{loop}	PLL Loop filter bandwidth	High Bandwidth	1.4		MHz
t _J	RMS Clock Jitter on Bit Clock output			2	ps peak

Digital Input and Output Characteristics

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm $\pm 1\%$; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 50$ MHz; $f_S = 50$ MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symbol	Parameter	Conditions	Typical (Note 4)	Limits	Units
Digital Ir	nputs (S _{DATA} , S _{SEL} , S _{CLK} , SLEEP, RS	Γ)		•	
V _{IH}	Logical input "1" voltage	Test run at 2MHz		900	mV (min)
V _{IL}	Logical input "0" voltage	Test run at 2MHz		300	mV (max)
I _{IN1}	Logical "1" Input current			1	μΑ (max)
I _{INO}	Logical "0" Input current			-1	μA (min)
C _{IN}	Input Capacitance	Guaranteed by design	5		pF
Digital O	Outputs (S _{DATA})				
V _{OH}	Logical output "1" voltage	Test run at 2MHz, V _{DR} = 1.2V	V _{DR}	850	mV (min)
V _{OL}	Logical output "0" voltage	Test run at 2MHz, V _{DR} = 1.2V	DRGND	250	mV (max)
I _{OH}	Logical "1" Output Current			-0.75	mA (min)
I _{OL}	Logical "0" Output Current			1	mA (max)
Output D	Drive Capability (S _{DATA})				
	Lood conscitours	R = 4.7 kohm, V _{DR} > 1.8V	50		pF
C_{LOAD}	Load capacitance	R = 4.7 kohm, V _{DR} = 1.2V	50		pF
Open Dr	ain Mode				
V_{EXT}	Maximum allowed external voltage on S _{DATA}	Open Drain mode activated		2.5	V
R _{SDATA}	Recommended S _{DATA} external pull- up resistor	Open Drain mode activated	4.7		kΩ

AC and Timing Characteristics

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm ±1%; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 50$ MHz; $f_S = 50$ MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symbol	Parameter	Conditions	Typical (Note 4)	Limits	Units
General	ADC Output Timing Parameters				
f _s	Sample Rate			40	MSPS (min)
's	·			50	MSPS (max)
	Conversion Latency		19		Samples
t _{BCLK}	Bit clock period	f _{CLK} = 50MHz	3.33		ns
		f _{CLK} = 40MHz	4.16		ns
t _{WCLK}	Word clock period	$f_{CLK} = 50MHz$	20		ns
		$f_{CLK} = 40MHz$	25		ns
t _s	Outputs Data Edge to Output Clock	$f_{CLK} = 50MHz$	800	325	ps (min)
	Edge Setup Time	f _{CLK} = 40MHz (Note 7)	900	480	ps (min)
t _H	Output Data Edge to Output Clock	f _{CLK} = 50MHz	850	470	ps (min)
	Edge Hold Time	f _{CLK} = 40MHz (Note 7)	1150	770	ps (min)
t _{DV}	Output Data Valid Window	f _{CLK} = 50MHz (Note 7)	1380	885	ps (min)
		f _{CLK} = 40MHz (Note 7)	1820	1410	ps (min)
t _R , t _F	Output Rise/Fall time	f _{CLK} = 50MHz	320		ps (min)
t _{DFS}	Data Edge to Word Edge Skew	f _{CLK} = 50MHz	-295	-720	ps (min)
2. 0				220	ps (max)
LVDS O	utput Parameters, OCM = 0 (V _{DR} = 1.2	2V)			•
		LVDS mode, $I_drive[1:0] = 00 (2.5mA)$, $R_L =$	270		mV
		100Ω			
V _{OD}	Differential Output Voltage	LVDS mode, $I_{drive}[1:0] = 01$ (3.5mA), $R_{L} =$	370	318	mV (min)
·OD		100Ω		428	mV (max)
		LVDS mode, I_drive[1:0] = 11 (5.0mA), R _L =	520		mV
		100Ω			
V _{OCM}	Output Common Mode Voltage	LVDS mode, OCM = 0 (for $V_{DR} = 1.2V$)	945	895	mV (min)
				1000	mV (max)
LVDS O	utput Parameters, OCM = 1 (V _{DR} = 1.8	BV)			1
		LVDS mode, $I_{drive}[1:0] = 00 (2.5mA), R_{L} =$	265		mV
		100Ω			
V _{OD}	Differential Output Voltage	LVDS mode, $I_{drive}[1:0] = 01$ (3.5mA), $R_{L} =$	350	280	mV (min)
· OD	Dinoronial Galpat Voltage	100Ω		417	mV (max)
		LVDS mode, I_drive[1:0] = 11 (5.0mA), R _L =	485		mV
		100Ω			
V_{OCM}	Output Common Mode Voltage	LVDS mode, OCM = 1	1265	1200	mV (min)
				1340	mv (max)
SLVS O	utput Parameters	1		T	
		SLVS mode, I_drive[1:0] = 00 (2.5mA), R _L =	245		mV
		100Ω			
V _{OD}	Differential Output Voltage	SLVS mode, I_drive[1:0] = 01 (3.5mA), R _L =	330	262	mV (min)
- טט		100Ω		393	mV (max)
		SLVS mode, I_drive[1:0] = 11 (5.0mA), R _L =	475		mV
		100Ω			
V _{OCM}	Output Common Mode Voltage	SLVS mode	225	185	mV (min)
OCM	Catput Common wode voltage	OL VO IIIOGO	220	270	mV (max)

AC and Timing Characteristics (Serial Interface)

Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $R_{REF} = 10$ kohm $\pm 1\%$; $C_L = 5$ pF; 100Ω terminated at the receiver; $f_{CLK} = 50$ MHz; $f_S = 50$ MSPS. **Boldface limits** apply for $T_A = T_{MIN}$ to T_{MAX} ; All other limits apply for $T_A = +25$ °C.

Symb	Parameter	Conditions	Typical (Note 4)	Limits	Units			
Serial I	Serial Interface							
t _{SSELS}	S _{SEL} setup time		250		ns			
t _{SSELH}	S _{SEL} hold time		250		ns			
t _{WS}	S _{DATA} setup time, write transaction		250	15	ns (max)			
t _{WH}	S _{DATA} hold time, write transaction		250	10	ns (max)			
t _{SCLK}	S _{CLK} period		1	0.2	μs (min)			
t _{SCLKL}	S _{CLK} low time		450		ns (min)			
t _{SCLKH}	S _{CLK} high time		450		ns (min)			
t _{SCLKR}	S _{CLK} rise time		50		ns			
t _{SCLKF}	S _{CLK} fall time		50		ns			
t _{SSELHI}	S _{SEL} high time	Applies to read and write transactions	500		ns			
t _{RS}	S _{DATA} valid setup time, read		100	-5	ns (min)			
	transaction		100	-5	113 (111111)			
t _{RH}	S _{DATA} valid hold time, read transaction		250	10	ns (min)			

Note 1: Absolute maximum ratings are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits.

Note 2: Operating Ratings indicate conditions for which the device is guaranteed to be functional, but do not guarantee specific performance limits. Guaranteed specifications and test conditions are specified in the Electrical Characterisitcs section. Operation of the device beyond the Operating Ratings is not recommended as it may degrade the device lifetime.

Note 3: All voltages are measured with respect to GND = AGND = DGND = 0V, unless otherwise specified.

Note 4: Typical figures are at TA = 25°C, and represent most likely parametric norms at the time of product characterization. The typical specifications are not guaranteed.

Note 5: This parameter is specified in dBFS. This indicates the value which would be obtained with a full-scale input.

Note 6: As the filter is a digital circuit, Digital Decimation Filter Characteristics scale with input clock frequency, f_{CLK}.

Note 7: This parameter is guaranteed by design and/or characterization and is not tested in production.

Note 8: The combination of common mode and voltage swing on the clock input must ensure that the positive voltage peaks are not above VDR and the negative voltage peaks are not below AGND.

Note 9: See the "Clock Conditioner Owner's Manual", Chapter 2 (www.national.com/appinfo/interface/files/clk_conditioner_owners_manual.pdf) for a discussion on iitter.

Timing Diagrams

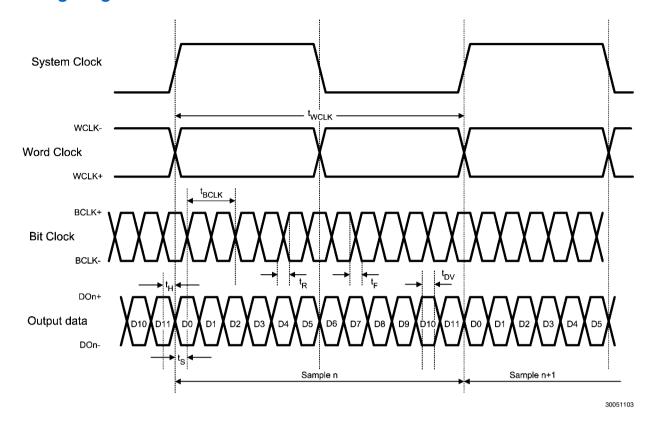


FIGURE 1. LVDS/SLVS Output Timing

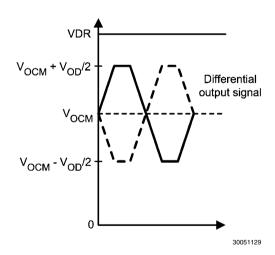


FIGURE 2. Output Level Definitions

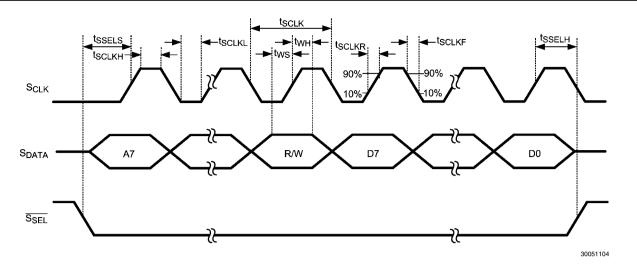


FIGURE 3. SPI Write Timing

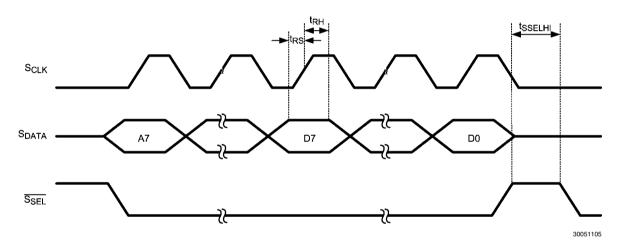
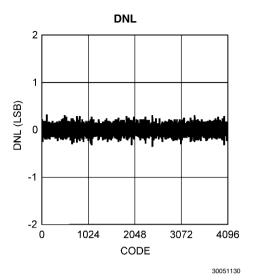
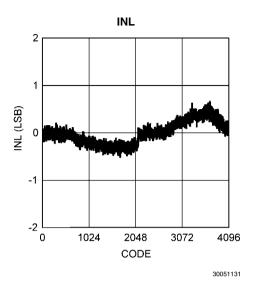
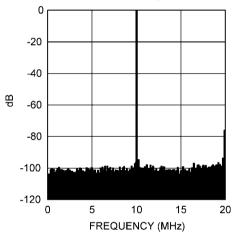


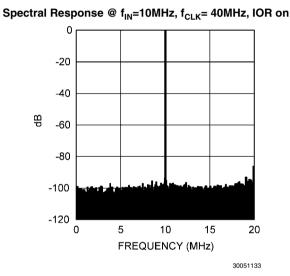
FIGURE 4. SPI Read Timing



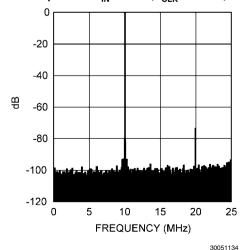


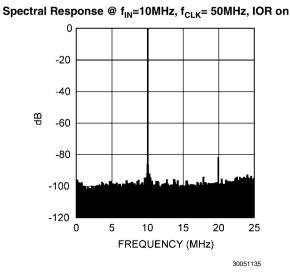
Spectral Response @ f_{IN}=10MHz, f_{CLK}= 40MHz, IOR off



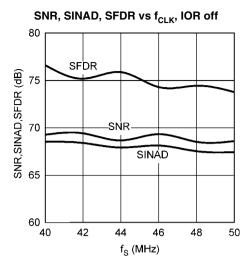


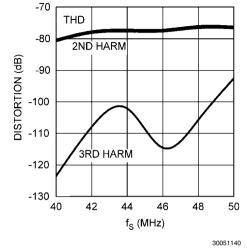
Spectral Response @ f_{IN} =10MHz, f_{CLK} = 50MHz, IOR off





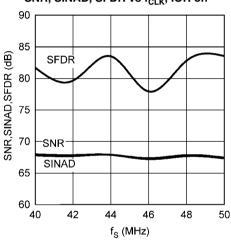
Typical Performance Characteristics Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $C_L = 5pF$; $f_{CLK} = 50MHz$; $f_S = 50MSPS$; $f_{IN} = 10MHz$. Units for SNR and SINAD are dBFS. Units for SFDR and Distortion are dBc.

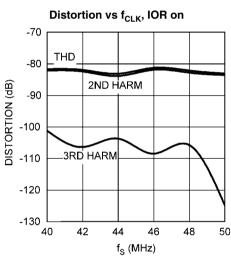




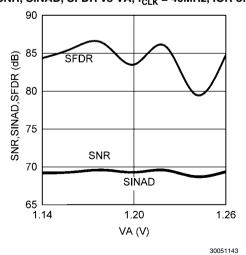
Distortion vs f_{CLK}, IOR off

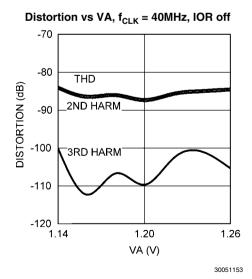
SNR, SINAD, SFDR vs $\mathbf{f}_{\text{CLK}},$ IOR on





SNR, SINAD, SFDR vs VA, $f_{CLK} = 40MHz$, IOR off



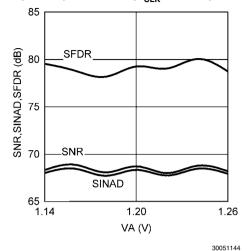


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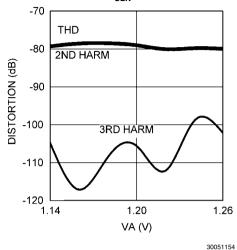
17

Typical Performance Characteristics Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $C_L = 5pF$; $f_{CLK} = 50MHz$; $f_S = 50MSPS$; $f_{IN} = 10MHz$. Units for SNR and SINAD are dBFS. Units for SFDR and Distortion are dBc.

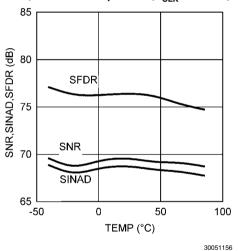
SNR, SINAD, SFDR vs VA, $f_{CLK} = 50MHz$, IOR off



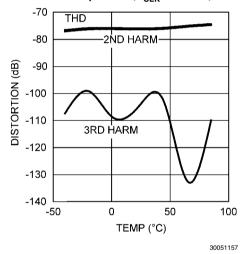
Distortion vs VA, $f_{CLK} = 50MHz$, IOR off



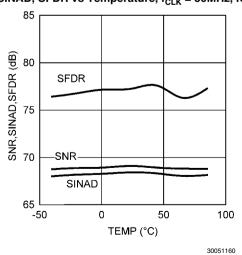
SNR, SINAD, SFDR vs Temperature, $f_{CLK} = 40MHz$, IOR off



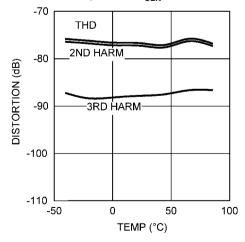
Distortion vs Temperature, f_{CLK} = 40MHz, IOR off



SNR, SINAD, SFDR vs Temperature, $f_{CLK} = 50MHz$, IOR off



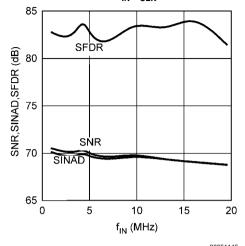
Distortion vs Temperature, f_{CLK} = 50MHz, IOR off



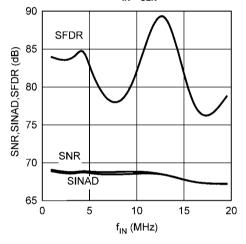
30051161

Typical Performance Characteristics Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $C_L = 5pF$; $f_{CLK} = 50MHz$; $f_S = 50MSPS$; $f_{IN} = 10MHz$. Units for SNR and SINAD are dBFS. Units for SFDR and Distortion are dBc.

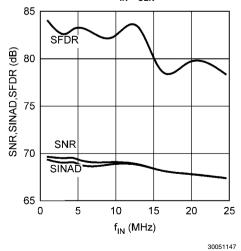
SNR, SINAD, SFDR vs f_{IN} , $f_{CLK} = 40MHz$, IOR off



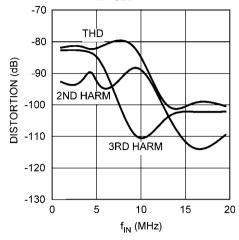
SNR, SINAD, SFDR vs f_{IN} , $f_{CLK} = 40MHz$, IOR on



SNR, SINAD, SFDR vs f_{IN} , $f_{CLK} = 50MHz$, IOR off

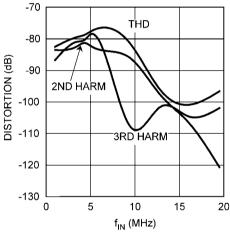


Distortion vs f_{IN} , $f_{CLK} = 40MHz$, IOR off



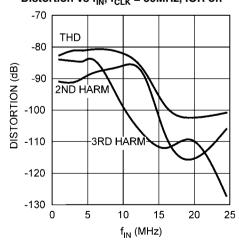
30051146

Distortion vs f_{IN} , $f_{CLK} = 40MHz$, IOR on



30051148

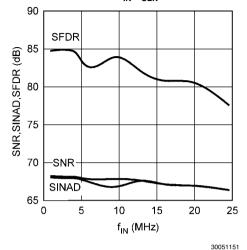
Distortion vs f_{IN} , $f_{CLK} = 50MHz$, IOR off



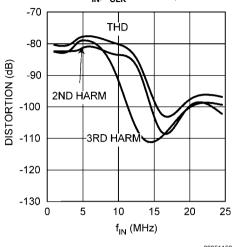
30051150

Typical Performance Characteristics Unless otherwise specified, the following conditions apply: $V_A = V_D = 1.2V$; $V_{DR} = 1.2V$; $V_{REF} = internal$; $C_L = 5pF$; $f_{CLK} = 50MHz$; $f_S = 50MSPS$; $f_{IN} = 10MHz$. Units for SNR and SINAD are dBFS. Units for SFDR and Distortion are dBc.

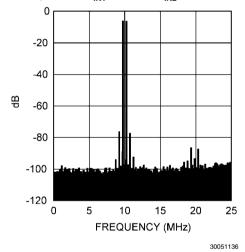
SNR, SINAD, SFDR vs f_{IN} , $f_{CLK} = 50MHz$, IOR on

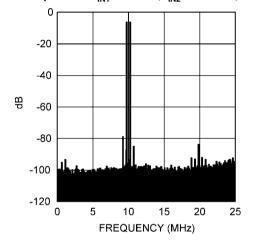


Distortion vs f_{IN} , $f_{CLK} = 50MHz$, IOR on

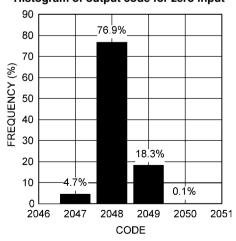


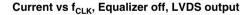
Spectral Response @ f_{IN1} = 9.6MHz, f_{IN2} = 10.1MHz, IOR off Spectral Response @ f_{IN1} = 9.6MHz, f_{IN2} = 10.1MHz, IOR on

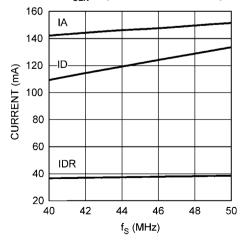




Histogram of output code for zero input







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Functional Description

The ADC12EU050 employs a number of unique strategies to provide a high performance multi-channel ADC that offers a significant power consumption reduction when compared to compteting architectures, as well as easing system level design. The ultra-low power performance of the ADC12EU050 is derived from the implementation of a fast continuous time sigma delta ($\text{CT}\Sigma\Delta$) modulator. Other features of this technology are:

- Intrinsic anti-alias filter the digital decimating filter provides an intrinsic anti-alias filter, eliminating external analog filter components, and simplifying multi-channel designs.
- Instant overload recovery (IOR) system guarantees extremely fast recovery from overload (<1ps), and no settling errors on return from overload.
- · Ultra-low inter-channel crosstalk.
- Digital Equalizer provides low group delay and hence minimizes signal path delay variation.

The major signal path blocks are: clipping control; CT∑∆ modulator; digital decimation filter; 12 bit serializer; and finally the LVDS/SLVS outputs. The PLL is critical to the operation of the ADC12EU050, and the PLL also provides the bit and word clock outputs. The SPI Control Interface gives uncomplicated user access to the ADC registers.

1.0 12-BIT SIGMA DELTA ADC CORE

The ADC12EU050 comprises eight analog ADC channels using a CT∑∆ architecture, which provides very high dynamic performance with ultra-low power, while operating from a minimal 1.2V supply.

The CTΣΔ ADC architecture uses a third order sigma delta modulator operating at a nominal 16 times over-sampling rate in combination with a 3-bit quantizer. The modulator output is coupled to a power efficient digital decimation filter that decimates the high rate modulator output (640 to 800MHz) to provide output data at a sample rate between 40 MSPS and 50 MSPS.

A benefit of the CT∑∆ design is that the ADC requires no external anti-alias filters for most applications. This benefit is derived from a combination of the design of the analog sigma delta modulator and digital decimation filter. The digital filter achieves a steep transition band, and provides 72 dB of attenuation in the stop band. Using the digital equalizer, the signal transfer characteristics including phase performance can be optimized so as to minimise group delay variation. In applications where it is not required, the digital equalizer can be disabled to further save power.

1.1 DIFFERENTIAL INPUT STAGE

The ADC can capture high speed analog signals without resorting to a complex fast sample-and-hold amplifier (SHA) as used in pipeline ADCs. This is where $CT\sum\Delta$ technology derives much of its power and performance benefits. This feature also assists external circuit design. In the case of the SHA inputs of pipeline ADCs, the effective input capacitance is time variant, requiring a powerful input buffer to drive to the resolution limits of the system. The input stage of the ADC is purely resistive (1.3k Ω single ended) driving into virtual earth. As a result the ADC12EU050 is extremely easy to drive as its input impedance is not complex. It also means that external lower power input buffering circuitry can used, and can be completely eliminated in some cases.

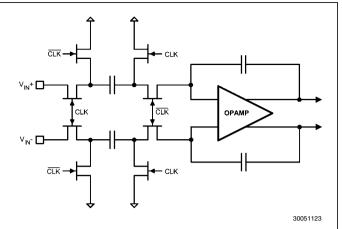


FIGURE 5. SHA Input Stage

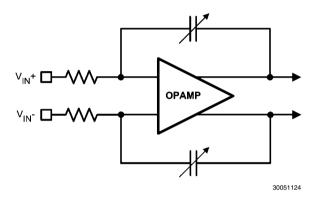


FIGURE 6. Continuous Time Sigma Delta Input Stage

1.2 INSTANT OVERLOAD RECOVERY

The ADC12EU050 features an overload handling system which provides instantaneous recovery from signals driving the ADC inputs beyond the full-scale input range. The ADC can operate in two different modes. In the default ADC mode (IOR mode off) a full-scale input range of 2.10 $\rm V_{\rm PP}$ is supported, here the ADC operates with some inherent overload recovery time, similar to a conventional ADC.

In the IOR mode, the ADC has a reduced 1.56 V_{PP} full scale input range, but provides a significant benefit in that the ADC can now be driven by input voltages as high as 5 dB beyond the nominal full-scale ($f_{\rm IN} <$ 12MHz), that is 2.75 $V_{\rm PP},$ and will recover instantaneously. In a number of applications this feature can help simplify input stage design and manufacturing set-up and calibration. The ADC12EU050 recovers immediately from overload with no missing codes and no settling time.

The proprietary strategy used within the ADC12EU050 uses high speed patented clamp techniques to limit the input signal and keep it within the stable input range of the ADC. This process happens at a speed equivalent to the on-chip oversampling rate of 640 to 800 MHz. The advantage of this system is that it responds immediately to out of range signals. While the inputs are over-range the ADC outputs a full scale result. As the over-range input is removed the ADC adjusts to the input signal level and is able to provide sampled data instantaneously. The ADC's behaviour on emerging from overload is repeatable and independent of whether the input signal was positive or negative going at the point of overload. The diagram below shows a 5dB overloaded input (2.75 $\rm V_{\rm PP}$ versus 1.56 $\rm V_{\rm PP}$ Full scale), with 240,000 sample periods

overlaid. There is no ringing and recovery from overload is instantaneous.

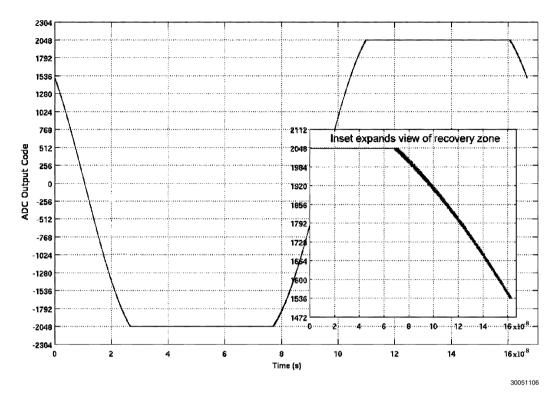


FIGURE 7. Instant Overload Recovery

1.3 INTEGRATED PRECISION LC PLL

The ADC12EU050 family includes an integrated high performance "clean up" phase locked loop (PLL), simplifying the need for a low jitter external clock. The PLL serves three important functions; it generates a highly accurate internal sampling clock source of up to 800 MHz; a clock for the LVDS serializers at 600 MHz; and it provides a low jitter clock for other internal components. With its jitter clean-up capability this PLL allows lower performance system clocks to be used.

1.4 DIGITAL DECIMATION FILTER AND EQUALIZER

The digital decimation filter is an integral part of the sigma delta architecture. It decimates the over-sampled data from the modulator down to the sample rate, and its extremely sharp low pass characteristic combined with the modulator's broad band response provides the intrinsic anti-alias filter. The digital low pass filter exhibits 72dB of attenuation in the stop band. The following diagram shows the digital filter transfer function at 40MSPS, compared to a third order Butterworth transfer function. Due to the digital implementation of the filter, the filter parameters automatically scale with the ADC sampling frequency.

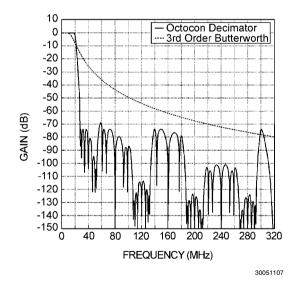


FIGURE 8. Digital Filter Transfer Function

Such steep digital filters introduce group delay problems, but the ADC12EU050 includes a digital equalizer, which reduces group delay ripple variation to less than 0.05 samples. In applications where group delay is not of concern, the equalizer can be turned off through the SPI interface in order to save power.

The following two diagrams show the group delay ripple of the digital decimation filter at 50MSPS, firstly with the equalizer disabled, and secondly with the equalizer enabled.

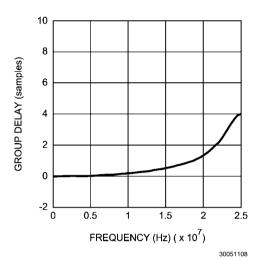


FIGURE 9. Group Delay with Equalizer Off

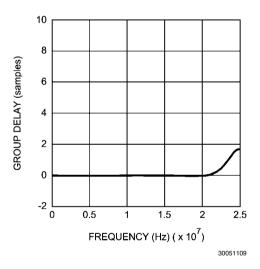


FIGURE 10. Group Delay with Equalizer On

1.5 SERIAL DATA OUTPUTS

Sampled data is transformed into high speed serial LVDS/ SLVS output data streams. The low amplitude differential signal swings of LVDS/SLVS help to reduce digital system noise. It is possible to select between LVDS and SLVS modes by simple programming through the SPI control interface. The output common mode can also be programmed through the SPI control interface, allowing it to be adjusted based on the value of $V_{\rm DB}$.

1.6 POWER MANAGEMENT MODES

The ADC12EU050 operates normally at ultra-low power levels. In addition, several power management modes are provided:

- Power Down (accessible through PD bit of Top Control Register)
- Sleep (SLEEP pin, or SLEEP bit of Top Control Register)
- Single channel power down (PD0-7 of ADC/LVDS Channel Power Down Register)

Power Down is the lowest power consumption mode, but with a longer wake-up time than Sleep mode. In power down mode, all circuits in the chip are turned off, including the PLL, reference and bias circuits.

Power consumption in Sleep mode is higher than in Power Down mode, but pin access (SLEEP pin) and fast wake-up enables duty cycle powering of the ADC.

The device also allows channel by channel power-down through the ADC/LVDS Channel Power Down register. When a single channel is powered down, the sigma delta modulator, digital decimating filter and LVDS outputs for that channel will be shut off, with the corresponding single channel reduction in power consumption.

1.7 SPI CONTROL INTERFACE

The ADC12EU050 provides configurability via the serial control interface. This provides IOR mode control power management control, output configuration control, data output test patterns to provide LVDS/SLVS training sequences, as well as many other user configurable options. Full details of the SPI registers can be found in the Programming Guide section of this datasheet.

The SPI pins (S_{DATA} , S_{CLK} , S_{SEL}), as well as the pins RST and SLEEP, have been designed to operate with voltage levels up to 2.5V, despite the low 1.2V core voltage. As a result, no external level shift components are required for this control interface.

1.8 UNCORRELATED NOISE REFERENCE FOR EACH CHANNEL

In many early multi-channel ADC designs, a single voltage reference was used to provide the reference level for each channel. Unfortunately, this ensures that the noise at each ADC's reference terminal is cross correlated. Multi-channel systems often make use of a 3 dB processing gain increase that results from each channel doubling. Without a specific technique to prevent the reference terminals seeing correlated noise the expected 3 dB gain is compromised. In the case of the ADC12EU050, a unique system has been implemented to de-correlate the noise at each ADC channel.

Application Information

2.0 POWER-UP SEQUENCE

The ADC12EU050 has three separate power supplies: Analog (V_A) , Digital (V_D) and the output drive voltage (V_{DR}) . The ADC contains a power on reset circuit, connected to VA, and so to ensure correct reset of both analog and digital logic of the ADC, the power supplies should be provided in the following order:

- 1. V_{DR}
- 2. V_D
- 3. V_A

If this order is not followed, then the user should issue a reset via the reset pin (RST) immediately after power up.

Additionally, it is required that the rise time for each voltage supply is longer than the minimum rise time stated in the Electrical Specifications section of this data sheet.

There is no required sequence for powering down the ADC.

2.1 ADC START-UP SEQUENCE

After any reset, either power-on reset, software reset via SPI or hardware reset via the RST pin, the chip undergoes a series of internal calibrations and the PLL/VCO will lock to the external clock.

After reset, the ADC12EU050's registers have the default values shown in register tables. The registers can be programmed via the SPI after reset, even during the period while the chip is performing the internal calibrations mentioned in the previous paragraph.

During reset and until the PLL is locked, the LVDS outputs will not provide valid data. Furthermore, the ADC has an inherent data conversion latency, which is related to the pipeline stages of the digital decimating filter. Until the data conversion latency has passed, the data outputs will be invalid.

Thus the maximum time until valid sampled data is received at the outputs is:

PLL lock time + ADC Latency

Specific values for these times can be found in the Electrical Specifications section of this datasheet.

2.2 USING ADC LOW POWER MODES

As explained previously in the Functional Description, the ADC12EU050 offers several power management modes.

Sleep mode offers the fastest wake-up time, and should be used in applications where duty cycle powering of the ADC is required. In this case it is recommended to toggle sleep mode via the SLEEP pin, which will give a faster cycle time than programming the SLEEP bit through the SPI, due to the extra time required to send a command through the SPI port.

The Power Down mode is accessible via the SPI port. Due to the power-up time of the ADC coupled with the programming time of the SPI port, this mode should be used to power the chip down for longer time periods.

Channel power down allows one or more channels to be turned off independently, with the corresponding power saving.

2.3 CLOCK SELECTION CONSIDERATIONS

The ADC12EU050 has an on-chip PLL, which simplifies the task of clock source selection and clock network design.

Clock Input Connection

The ADC is designed to accept either single ended or differential clock inputs. Furthermore, the clock source can be a sine or square wave. In order to obtain the best performance,

a differential square wave clock should be used. When using a differential clock, the clock traces should be routed as 100Ω differential pairs, and terminated with a 100Ω resistor close to the chip. A single ended clock input should be connected to pin 47 (CLK+/SE), and pin 48 (CLK-) should be grounded.

On-chip PLL

The benefit of having an on chip PLL is that in most applications a high precision clock source is not required. The external clock's contribution to aperture jitter is reduced dramatically by the jitter clean-up properties of the PLL, which ensures that any RMS jitter outside of the PLL bandwidth is attenuated. The PLL also significantly relaxes the input clock duty cycle requirements, accepting input clock duty cycles of 20% to 80%.

The PLL offers two choices of bandwidth. For the majority of systems, the default bandwidth of 400kHz is suitable. If the system already contains a high performance clock, with excellent RMS jitter performance up to a 1.4MHz bandwidth, then the PLL's high bandwidth mode may be used.

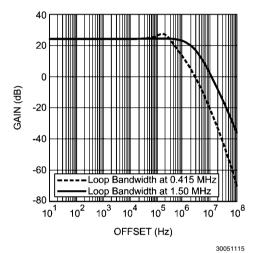


FIGURE 11. PLL Phase Noise Transfer Function: $f_s = 40MHz$

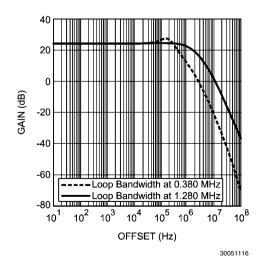


FIGURE 12. PLL Phase Noise Transfer Function: $f_s = 50MHz$

On the input clock, excessive RMS jitter within the PLL bandwidth will be seen in the output spectrum as sidebands, or close in phase noise, around the fundamental signal.

Input Clock Selection

For systems which do not have a requirement for a high performance clock, any standard product 40MHz – 50MHz crystal oscillator will allow the ADC12EU050 to perform to specifications. If the system requires high performance clocks for other system components, then National Semiconductor's LMK family of clock conditioners are recommended.

Output Clock Synchronization Across Multiple Chips

In systems containing more than one ADC12EU050, it is often required that the timing of output samples is synchronized across the multiple chips. The PLL in the ADC12EU050 takes care of this automatically by aligning the output clocks with the input clock. The user must ensure, using correct board layout and clock buffering techniques, that the input clock to

each ADC12EU050 is synchronized. If this is the case, then the output frame clocks will also be synchronized. This means that output samples are aligned.

2.4 ADC INPUT CONSIDERATIONS

The ADC12EU050's sigma delta architecture offers many flexible options for connecting input signals.

In order to obtain maximum performance from the device, it is recommended to use a differential input connection. The device, however, also supports single ended analog input.

Differential Input Configurations

The ADC12EU050 can be driven either actively or passively. Transformer coupling provides another possibility for converting a single ended signal into a differential signal. The diagram below shows a transformer coupled input configuration.

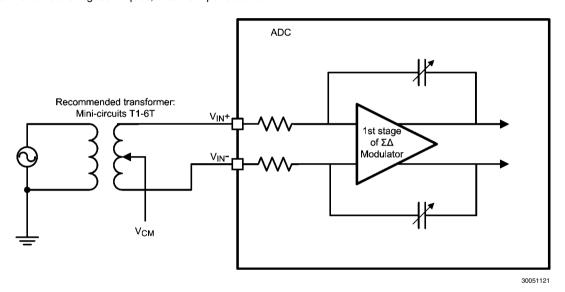


FIGURE 13. Transformer Coupled Input

Single Ended Input Configurations

In cost sensitive applications, a single ended input may provide adequate performance, however ADC performance will degrade slightly. When using single ended inputs, the maximum single ended inputs are single ended inputs.

mum input voltage allowed is 3dB less than the 2.10V full scale input. The diagram below shows a single ended input configuration.

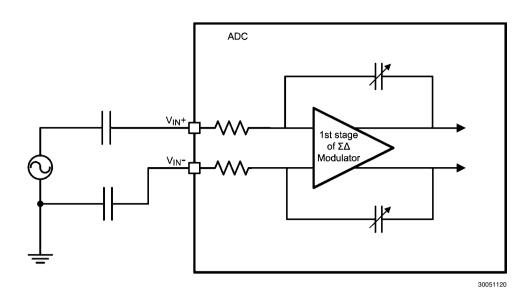


FIGURE 14. Single Ended Input

Input Coupling and Common Mode

The ADC12EU050 internally generates a common mode of 0.62V. It is possible to provide input signals with other common modes however, the full scale input range of the ADC must be kept in mind.

For this reason, it is recommended that the device inputs are AC coupled. The recommended capacitor value is 100nF.

chitecture, the ADC12EU050 allows the user to scale down large input signals by adding external series resistors. The gain achieved by adding external resistors can be calculated as a simple voltage divider, as follows:

Due to the purely resistive input circuit of the sigma delta ar-

 V_{FS}/V_{IN} = 20 * log (R_{ADC} /(R_{ADC} + R_{EXT})) dB The diagram below shows this configuration, and defines the values in the equation above.

External Series Resistance

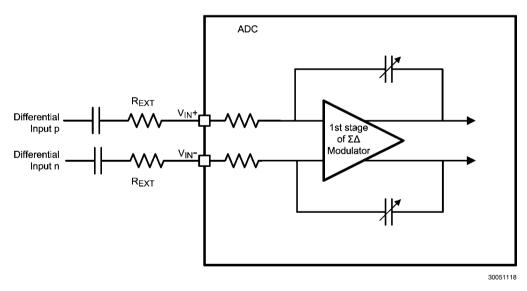


FIGURE 15. External Series Resistance

 R_{ADC} , the input resistance of the ADC, is nominally 1.3k Ω . Due to manufacturing the value of this resistance can vary by up to 15%. This is not important for the operation of the ADC, since the ADC depends only on internal resistors being matched, but it should be taken into account when performing calculations.

2.5 ADC OUTPUT CONSIDERATIONS

The ADC12EU050 offers a variety of output settings in order to cater for different system design and integration needs.

Output Driver Voltage, VDR

The ADC output driver voltage, VDR, can be set between 1.2V and 1.8V. A VDR of 1.2V will offer the lowest power consumption. Because VDR can be varied, the ADC12EU050 provides, via the SPI registers, the ability to adjust the output common mode voltage.

Output Modes And Output Common Mode

Three different output modes are also supported: SLVS, LVDS and reduced common mode LVDS. SLVS and LVDS modes output data according to their respective specifications.

Reduced common mode LVDS must be used when the output driver voltage, VDR, is 1.2V. The standard LVDS common mode voltage is 1.2V, which is obviously not feasible if VDR is 1.2V. Therefore, the output common mode voltage must be set to 1.0V by setting the bit OCM in the LVDS Control Register to 0.

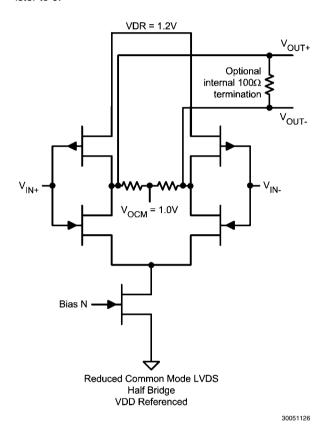


FIGURE 16. Output Driver Circuit: Reduced Common Mode LVDS

When VDR is 1.8V, the standard LVDS common mode voltage of 1.2V must be used, by setting OCM equal to 1.

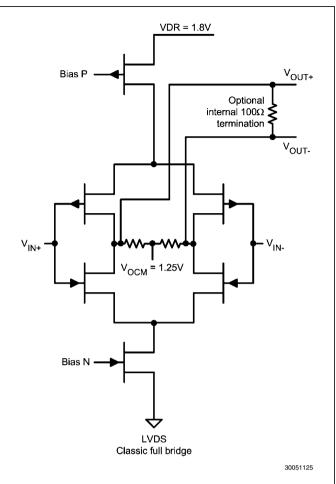


FIGURE 17. Output Driver Circuit: LVDS

SLVS mode offers the lowest power consumption, followed by reduced common mode LVDS then standard LVDS.

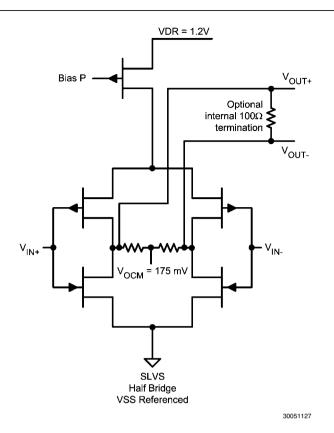


FIGURE 18. Output Driver Circuit: SLVS

As well as the different output modes, the output drive current can also be controlled via the LVDS Control Register. The default output drive current is 2.5mA, but this can be increased to 3.5mA or 5mA, depending on output trace routing and receiver requirements. Power consumption of the AD-C12EU050 will increase slightly as the output driver current is increased.

Termination

The final control feature available in the LVDS Control Register is the choice between internal and external 100Ω termination. Although the termination is recommended to be as close to the receiver as possible, in some cases it may be necessary or desirable to perform this termination at the transmitter. Internal 100Ω termination at the transmitter (the ADC12EU050) is enabled by setting the bit TX_term to 1.

LVDS Output Training Sequences

Often it is necessary to calibrate the LVDS receiver, for example an FPGA or DSP, so that skew between the eight ADC output channels is minimized. In order to simplify this process, the ADC12EU050 provides three LVDS training modes, where a pre-defined or custom pattern is output on all eight channels simultaneously. While a training mode is active, the word and bit clocks are output as usual. In order to select a training mode, the TSEL bits of the Decimator Control Register (16h) must be programmed via the SPI interface.

There are two pre-defined training patterns, or a custom pattern can be loaded via the SPI into the Serializer Custom Pattern 0 and 1 Registers (10h and 12h). In order to return to normal ADC operation after skew calibration, the TSEL bits should be returned to their default value of 00.

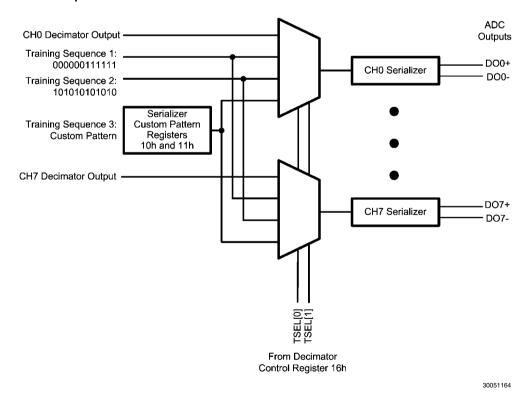


FIGURE 19. LVDS Training Select operation

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2.6 USING IOR MODE

As discussed in the Functional Description, IOR mode provides instantaneous recovery from overload conditions, with

no ringing and correct data output as soon as the input returns in range.

Standard Use of IOR Mode

The recommended way to enable IOR mode is by setting bit 4 (IOR) of the Modulator Overload Control register (04h). Setting this bit will enable IOR mode with the default settings for DGF in the Decimator Clipping Control register (14h) and OL in the Modulator Overload Control register (04h). Setting the IOR mode bit to 0 will restore DGF and OL to their default values, hence putting the chip back into ADC mode.

As can be seen in the Electrical Specifications, using IOR mode gives a slight reduction in SNR performance, and also a reduction of the full scale input range to 1.56Vpp differential.

Advanced Use of IOR Mode

The registers described above allow the user to customize IOR mode. In order to correctly set the DGF and OL values, it is necessary to understand how the IOR mode functions. The implementation of IOR mode in the ADC consists of analog and digital parts working in tandem.

The analog clipping circuitry, controlled by OL, is designed to protect the sigma delta modulator from large signal inputs.

Using an analog clamp, signals are soft-limited to the less than the 2.10Vpp full scale range of the modulator. OL gives the value at which the circuit will begin to clamp.

The digital filter of the ADC12EU050 is where the full scale input range is selected and the hard limiting of the signal takes place. DGF selects the gain of the digital filter, and hence the new full scale input range of the ADC.

In order to set a custom value for DGF, CGS, bit 7 of the Decimator Clipping Control register, must be set. The DGF can then be set, based on the application requirements.

OL should then be set to a value approximately half-way between the new full scale input range (which was just selected by DGF) and the default full scale input range of 2.10Vpp. OL must be set to a value higher than DGF, otherwise the signal will be limited by the analog clipping circuitry, rather than the digtal circuitry, and overload recovery will be impacted.

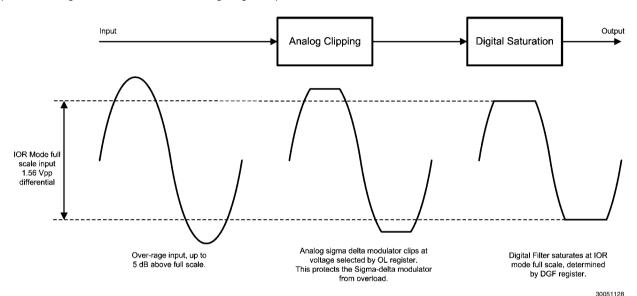


FIGURE 20. IOR Mode Signal Modification

2.7 THE VOLTAGE REFERENCE

The ADC provides an on chip, $\pm 5\%$ tolerance voltage reference, together with all necessary biasing circuits and current sources. A $10k\Omega$ ($\pm 1\%$) resistor must be connected between R_{REF} and AGND in order to establish the biasing current of the ADC. The internal reference voltage, V_{REF}, is available at the R_{REF} pin.

When using the internal reference, V_{REFT} should be connected to AGND through a 100nF capacitor, while V_{REFB} must be connected to AGND.

Chip-to-chip gain matching between several ADC12EU050 ADCs can be improved by connecting the V_{REFT} pins of the ADCs. This is show in the figure below.

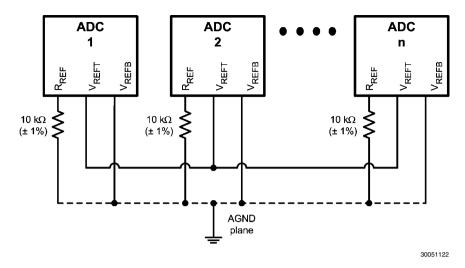


FIGURE 21. Reference Sharing

If a tighter tolerance reference is required for improved thermal stability, an external voltage reference can be connected between the V_{REFT} and V_{REFB} pins. The R_{REF} resistor must be connected even when using an external reference.

2.8 D_{CAP} CAPACITOR SELECTION

The D_{CAP} pin provides the capacitance for the low pass filter between the DAC bias block and the DAC in the sigma-delta modulator. The filter blocks noise from the DAC Bias block from entering the DAC. Any noise which passes through this filter will be seen in the spectrum as side skirts around the carrier. The filter circuit, which is a first order RC filter, is shown in the diagram below.

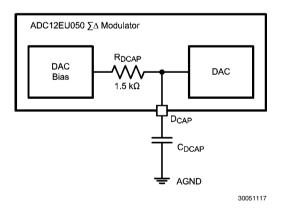


FIGURE 22. D_{CAP} RC Filter

The D_{CAP} pin must be connected to AGND through a low leakage, minimum 100nF capacitor. If the application is especially sensitive to close to the carrier phase noise, then it is recommended to increase D_{CAP} , up to a maximum of $10\mu F$. For other applications where close to the carrier phase noise is not important, the capacitor can be kept small in order to reduce costs and minimise board space. The corner frequency of this filter is determined by the equation:

 $f = 1/(2\pi R_{DCAP}C_{DCAP})$

2.9 BOARD LAYOUT CONSIDERATIONS

Proper grounding, layout and routing are essential to ensure accurate conversion in any high speed ADC.

Maintaining separate analog and digital areas of the board is recommended in order to achieve the specified performance. This includes using a split ground plane, since the significant digital portion of the chip can produce noise on the digital/IO ground (DGND).

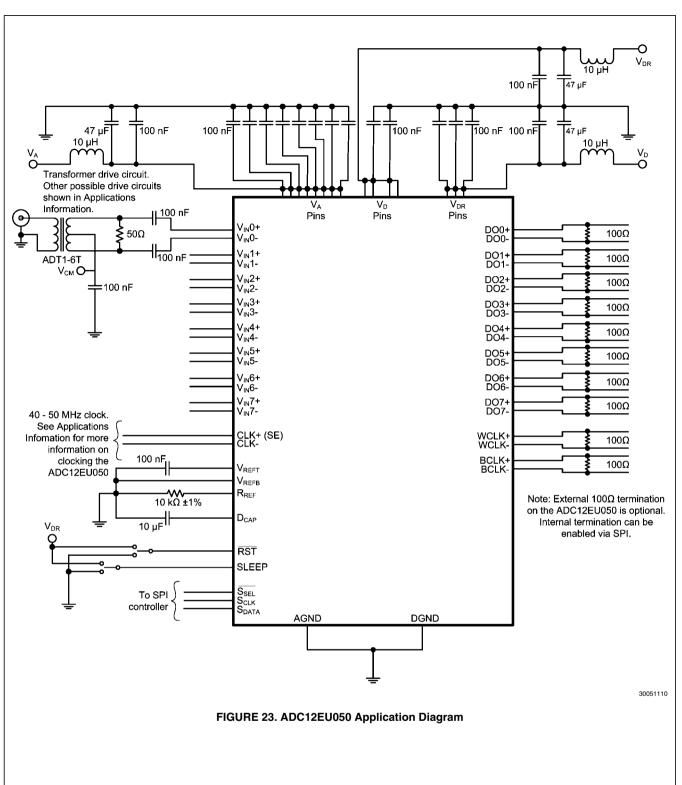
When designing the ADC12EU050 into a system, It is critical that the exposed pad is connected to analog ground (AGND). The exposed pad provides the analog ground connection for the ADC12EU050, and so this connection is required for electrical rather than thermal reasons.

It is recommended to decouple the power supplies using a large capacitor (e.g. 47µF) for low frequency noise, and small capacitors (e.g. 100nF) placed close to each supply pin.

Analog and digital supplies (V_A and V_D) may be provided from the same supply, however in this case it is recommended that the supplies are isolated from each other with a ferrite bead or inductor. If the IO driver supply (V_{DR}) is 1.2V, then it may also be taken from the same supply, with isolation as described above.

The clock and data output traces, as well as the clock input trace (when using a differential input clock), should be routed as 100Ω impedance differential pairs. If not using the option for 100Ω internal termination, then the clock and data output trances should be terminated with a 100Ω resistor close to the receiver.

If the system requires regulators to provide the ADC12EU050 1.2V operating voltage, National Semiconductor recommends the LP3878SD-ADJ Low Noise "Ceramic Stable" Adjustable Regulator or the LP3879 Low Noise "Ceramic Stable" Regulator. Datasheets for both parts are available from the National Semiconductor website.



Programming Guide

3.0 THE SERIAL CONTROL INTERFACE

The ADC12EU050 provides several user controlled functions which are accessed through a standard SPI compatible, 3 wire Serial Interface, as shown in the diagram below.

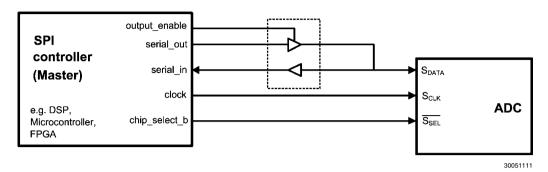


FIGURE 24. Three Wire Control Interface

Wired OR mode is supported in order to connect multiple AD-C12EU050 devices to one SPI Master. The clock and data buses are common to all ADC devices, and the chip select S_{SEL} is used to control which SPI is currently active. The SPI master must have a unique pin available for each ADC's S_{SFI} . The diagram below illustrates the connection.

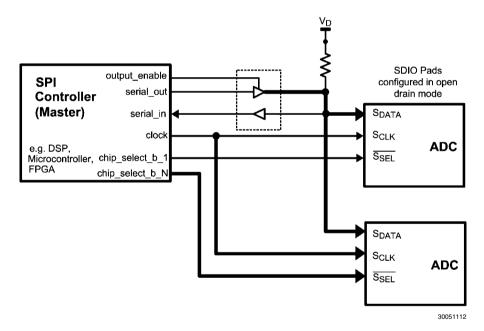
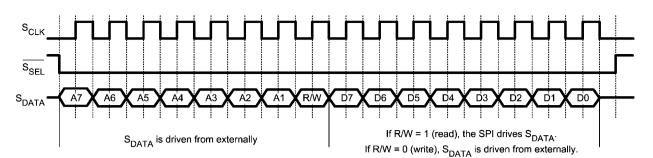


FIGURE 25. Multi-Wire Control Interface

When connecting multiple devices, the S_{DATA} pin must be set in Open Drain mode. Open Drain mode is enabled by setting the SPIOD bit in the Top Control Register of all connected ADC12EU050 devices. When S_{DATA} is in open drain mode, the user must ensure that a pull-up resistor is connected to the S_{DATA} bus. Further details on Open Drain mode are given in

3.1 SERIAL CONTROL INTERFACE PROTOCOL

Both read and write transactions are made up of eight address bits and eight data bits. The final address bit of the address phase determines whether the transaction will be a read transaction or a write transaction – logic level low for write, logic level high for read. The following diagram shows the protocol.



30051113

FIGURE 26. Serial Control Interface Protocol

below

The eight address bits, A[7:1] + R/W, are sent first. The data, D[7:0], is then sent for a write transaction, or D[7:0] is received for a read transaction. Address and data are sent and received with the most-significant-bit (MSB) first. The SPI is enabled using the active low input \mathbf{S}_{SEL} . If \mathbf{S}_{SEL} is high the SPI cannot be accessed, although \mathbf{S}_{SEL} is not a reset signal and registers will maintain their value when \mathbf{S}_{SEL} is toggled. \mathbf{S}_{SEL} must be held low during the entire transaction.

Timing requirements for the Serial Interface are described in the Electrical Characteristics section of this document.

3.2 SERIAL INTERFACE TRANSACTION CANCELLATION

A transaction may be cancelled before the address and data stages are completed by toggling S_{SEL} to high at any stage during an SPI access. This action is not recommended, as transaction cancellation during a write transaction may corrupt register contents and during a read transaction will result in incorrect data.

After canceling a transaction with S_{SEL} the ADC may be in an unknown state due to an incomplete and hence corrupted write to a register. It is therefore recommended to reset the chip via Software Reset (SRES) after a cancelled transaction.

3.3 S_{DATA} PAD OPEN DRAIN MODE

If the S_{DATA} voltage at the board level is required to be higher than the ADC12EU050's V_{DB} , the Open Drain mode should

be used. In Open Drain mode, the ADC's S_{DATA} will pull the output low, and S_{DATA} will be pulled up to the external level by a pull-up resistor connected to the board's positive voltage rail, VEXT.

The intended use of Open Drain mode is when the ADC, including V_{DR} , is running at 1.2V, and a VEXT of 1.8V is required.

Open Drain mode is enabled by setting the SPIOD bit in the Top Control Register via the Serial Interface. When in Open Drain mode, a pull-up resistor (RSDATA) must be connected between S_{DATA} and VEXT. The table of Electrical Specifications shows the required settings for VEXT and RSDATA.

3.4 SERIAL CONTROL INTERFACE READ AND WRITE SPEED

 S_{CLK} (pin 45) controls the speed of interaction with the ADC. The SPI interface supports write to and read from speeds as defined in the Electrical Specifications section of this document.

3.5 SERIAL CONTROL INTERFACE REGISTER DESCRIPTIONS

The following tables show the complete set of user accessible SPI registers, with descriptions of the functionality of each bit. Reset values of all registers are also described in the tables

Register Index

Address	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	Default	
Top Control Register										
00h	Reserved	Reserved	CBR	40/50	SRES	SPIOD	SLEEP	PD	00h	
ADC / LVD	ADC / LVDS Channel Power Down Register									
02h	PD7	PD6	PD5	PD4	PD3	PD2	PD1	PD0	00h	
Modulator	Modulator Overload Control Register									
04h	Reserved	Reserved	Reserved	IOR	OL[3]	OL[2]	OL[1]	OL[0]	00h	
PLL Contr	PLL Control Register									
08h	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	SHBW	STCAL	00h	
LVDS Inpu	t Clock Hyste	resis					,			
0Ah	Reserved	Reserved	INVCLK	100HYS	50HYS	20HYS	10HYSOFF	HYSOFF	00h	
Serializer (Serializer Custom Pattern 0 Register									
	Custom	Custom	Custom	Custom	Custom	Custom	Custom	Custom		
10h	Pattern	Pattern	Pattern	Pattern	Pattern	Pattern	Pattern	Pattern	00h	
	[7]	[6]	[5]	[4]	[3]	[2]	[1]	[0]		
Serializer (Serializer Custom Pattern 1 Register									
					Custom	Custom	Custom	Custom		
12h	Reserved	Reserved	Reserved	Reserved	Pattern	Pattern	Pattern	Pattern	00h	
					[11]	[10]	[9]	[8]		
Decimator Clipping Control Register										
14h	Reserved	Reserved	a[2]	a[1]	a[0]	b[2]	b[1]	b[0]	00h	
Decimator Control Register										
16h	Reserved	Reserved	Reserved	EQON	DFS	MSB	TSEL[1]	TSEL[0]	00h	
LVDS Control Register										
18h	Reserved	Reserved	Reserved	TX_term	I_drive[1]	I_drive[0]	OCM	SLVS	00h	
Chip ID Re	Chip ID Register									
1Eh	ID [7]	ID [6]	ID [5]	ID [4]	ID [3]	ID [2]	ID [1]	ID [0]		

Top Control Register

Address: 00h Attributes Write Only.

Register 01h reads back contents of register 00h, if CBR is set.

The Top Control Register is the basic initialization and control register for the device.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	Reserved		CBR	40/50	SRES	SPIOD	SLEEP	PD	
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description					
7:6	Reserved. Write as zero for future compatibility.					
5	CBR: Control Bus Read. When asserted register 00h (this register) can be read, but no other registers. When de-asserted all other registers can be read, but not register 00h.					
	0 Register 00h cannot be read from address 01h. All other registers can be read back. 1 Register 00h can be read from address 01h. All other registers cannot be read back.					
4	40/50: Selects the ADC sample rate. This bit should be set according to the applied input clock to obtain optimal performance.					
	0 45-50MSPS 1 40-45MSPS					
3	SRES: Software Reset. When asserted the software reset will reset the whole device. SRES performs the same function as the hardware reset (RST pin). The SRES is self clearing in approximately 2µs.					
	0 Software Reset Inactive 1 Software Reset Active					
2	SPIOD: SPI Open Drain mode. 0 Digital Logic Output					
	1 Open Drain Mode. Enables SPI Driver to operate above V _{DR}					
1	SLEEP: Sleep Mode. Powers down the device with the exception of the PLL and the reference blocks. The time to wake-up from sleep mode is $< 10 \mu s$.					
	0 Sleep Mode Inactive 1 Sleep Mode Active					
0	PD: Power Down Mode. Completely powers down the device. The power up time is approximately 20ms.					
	PD Mode Inactive, device operates normallyPD Mode Active, device powered down					

ADC / LVDS Channel Power Down Register

Address: 02h

Attributes Write Only.

Register 03h reads back contents of register 02h.

The ADC/LVDS Channel Power Down Register provides the capability to independently power down each ADC channel.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	PD7	PD6	PD5	PD4	PD3	PD2	PD1	PD0	
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7	PD7: Power Down Channel 7
	0 Channel Active
	1 Channel Power Down
6	PD6: Power Down Channel 6
	0 Channel Active
	1 Channel Power Down
5	PD5: Power Down Channel
	0 Channel Active
	1 Channel Power Down
4	PD4: Power Down Channel 4
	0 Channel Active
	1 Channel Power Down
3	PD3: Power Down Channel 3
	0 Channel Active
	1 Channel Power Down
2	PD2: Power Down Channel 2
	0 Channel Active
	1 Channel Power Down
1	PD1: Power Down Channel 1
	0 Channel Active
	1 Channel Power Down
0	PD0: Power Down Channel 0
	Ohammal Aatina
	0 Channel Active 1 Channel Power Down
	1 Channel Power Down

Modulator Overload Control Register

Address: 04h Attributes Write Only.

Register 05h reads back contents of register 04h.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	Reserved			IOR		OL[[3:0]		
Default	0	0	0	0	0	0	0	0	00 h

Bit	Des	cription							
7:5	Reserved. Write as zero for future compatibility.								
4	IOR: Enable IOR Mode (Instant Overload Rec	overy)							
	This bit can be used to quickly enable IOR mode with the default IOR settings for DGF (see register 14h) and OL.								
	0 IOR Mode Disabled								
	1 IOR Mode Enabled								
3:0	OL[3:0]: The bits define the differential peak voltage (in V _{PP}) at which the analog input signal is clipp when in IOR mode. In IOR mode the analog clipping is set to 1.746 V _{PP} . In the default ADC mode clipping of the analog input signal is disabled. Should it be decided to over-ride the default setting, it is important to follow the guidelines for sett OL, as described in the Applications Information section.								
	OL[3:0]	Clipping Voltage V _{PP}							
	0 (IOR Mode default)	1.746							
	0001	1.694							
	0010	1.64							
	0011	1.586							
	0100	1.534							
	0101	1.480							
	0110	1.426							
	0111	1.374							
	1000	2.172							
	1001	2.120							
	1010	2.066							
	1011	2.012							
	1100	1.960							
	1101	1.906							
	1110	1.852							
	1111	1.800							

PLL Control Register

Address: 08h Attributes Write Only.

Register 09h reads back contents of register 08h.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description			Res	erved			SHBW	STCAL	
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description							
7:2	Reserved. Write as zero for future compatibility.							
1	SHBW: Set PLL to High Bandwidth. The selection of the PLL bandwidth permits to set the sensitivity of the PLL to input clock jitter. Less bandwidth decreases the sensitivity to input clock jitter.							
	The PLL Bandwidth is related to the sampling frequency, the exact values of which can be found in the electrical specifications table.							
	The PLL will pass any input clock jitter up to the PLL bandwidth, while jitter above the PLL bandwidth will be attenuated. Low bandwidth mode should be used for high jitter input clocks, while high bandwidth mode can be used for high-quality, low jitter input clocks.							
	0 PLL bandwidth is set to Low Bandwidth (400kHz).							
	1 PLL bandwidth is set to High Bandwidth (1.4MHz).							
0	STCAL: Start VCO calibration. The calibration can be manually started in order to assure that the frequency tuning margin is maximum, for example, in case of large temperature change during operation it can be useful to restart the calibration.							
	The VCO calibration starts automatically if a Loss of Lock is detected							
	1 The VCO calibration is restarted.							

LVDS Input Clock – Hysteresis

Address: 0Ah
Attributes Write Only.

Register 0Bh reads back contents of register 0Ah.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	Rese	rved	INVCLK	100HYS	50HYS	20HYS	10HYS OFF	HYSOFF	
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:6	Reserved. Write as zero for future compatibility.
5	INVCLK: Invert Input Reference Clock. This bit is used to invert the input clock.
	0 Reference input clock not inverted.
	1 Reference input clock inverted.
4	100HYS: Enable 100mV hysteresis. This bit enables 100mV hysteresis. It should be used for a CMOS
	input clock only.
	0 Normal operation (10mV hysteresis)
	- The special Control of the special control
3	1 100mV hysteresis (CMOS input clock only)
3	50HYS: Enable 50mV hysteresis. This bit enables 50mV hysteresis. It should be used for a CMOS input clock only.
	input clock only.
	0 Normal operation (10mV hysteresis)
	1 50mV hysteresis. (CMOS input clock only)
2	20HYS: Enable 20mV hysteresis. This bit enables 20mV hysteresis. It should be used for an LVDS
	input clock only.
	0 Normal operation (10mV hysteresis)
	1 20mV hysteresis. (LVDS input clock only)
1	10HYSOFF: Disable 10mV hysteresis. 10mV hysteresis is the default setting. This bit is used to
	disable 10mV hysteresis, in the case where another hysteresis setting is desired, for example when
	using a CMOS input clock.
	0 10ml/ hyptograpic // V/DC imput alcal(anhu)
	0 10mV hysteresis. (LVDS input clock only)
	1 10mV hysteresis disabled.
0	HYSOFF: Disable all hysteresis settings. This bit is used to disable all hysteresis settings.
	0 Normal operation (10mV hysteresis)
	All hysteresis settings disabled.
	1 / All Hydrorodia deturings distanced.

Serializer Custom Pattern 0 Register

Address: 10h

Attributes Write Only.

Register 11h reads back contents of Register 10h.

This register in conjunction with User Register 12 provides storage for the custom de-skew pattern. See User Register 16 for a description of how this training sequence is used.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description		Custom Pattern [7:0]							
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:0	Custom Pattern [7:0]. This pattern forms the lower byte of Custom Pattern [11:0] which is output by
	the serializer when the Training Sequence Select bits (bits 1:0) of the Decimator Control Register are
	set to select Training sequence 3.

Serializer Custom Pattern 1 Register

Address: 12h

Attributes Write Only.

Register 13h reads back contents of Register 12h.

This register in conjunction with User Register 10 provides storage for the custom de-skew pattern. See User Register 16 for a description of how this training sequence is used.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	Reserved								
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:4	Reserved. Write as zero for future compatibility.
	Custom Pattern [11:8]. This pattern forms the upper 4 bits of Custom Pattern [11:0] which is output by the serializer when the Training Sequence Select bits (bits 1:0) of the Decimator Control Register are set to select Training sequence 3.

Decimator Clipping Control Register

Address: 14h Attributes Write Only.

Register 15h reads back contents of Register 14h.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	CGS	Reserved		a[2:0]			b[2:0]		
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7	CGS: Custom Gain Setting. This bit is used to override the automatic gain settings for ADC and IOR modes. If the user wishes to write a custom digital gain coefficient using a[2:0] and b[2:0] of this register, then the CGS bit must be set.
	0 Normal operation Automatic gain settings used
	1 Custom Gain Setting Gain setting from a[2:0] and b[2:0] used.
6	Reserved. Write as zero for future compatibility.
5:3	a[2:0]: Digital Gain Coefficient. In clipping mode the input range of an ADC channel is limited to 1.56Vpp. In ADC mode the input range is 2.10Vpp. The output of the digital filter has to be scaled according to the selected mode (the filter data has to be mapped in to the 12bit output data), the difference between 1.6Vpp and 2.2Vpp is -2.6dB, hence the digital filter gain has to be set to 2.6dB when in IOR mode and to 0dB when in clipping mode (default mode). This is performed by setting a Digital Gain Factor which is calculated using the following formula:
	$DGF = \frac{32 + 4 \times DGFa + DGFb}{26}$
	26
	The mapping of the coefficient values for a[2:0] is as follows:
	011 = Not used. Defaults to 2
	010 = 2
	001 = 1
	000 = 0
	111 = -1
	110 = -2
	101 = Not used. Defaults to -2
	100 = Not used. Defaults to -2
	The mapping of the coefficient values for b[2:0] is shown below. The table on the following page shows the available Digital Gain Coefficient settings.
2:0	b[2:0]: Digital Gain Coefficient.
	The mapping of the coefficient values for b[2:0] is as follows:
	011 = Not used. Defaults to 2
	010 = 2
	001 = 1
	000 = 0
	111 = -1
	110 = -2
	101 = Not used. Defaults to -2
	100 = Not used. Defaults to -2

Coefficent a[2:0]	Coefficent b[2:0]	Digital Gain (dB)	Equivalent full scale input range (V _{PP})	
010	010	4.16	1.30	
010	001	3.95	1.33	
010	000	3.74	1.37	
010	111	3.52	1.40	
010	110	3.29	1.44	
001	001	3.06	1.48	
001	000	2.82	1.52	
001	111	2.58	1.56	IOR Mode default setting
001	110	2.33	1.61	
000	001	2.07	1.65	
000	000	1.80	1.71	
000	111	1.53	1.76	
000	110	1.24	1.82	
111	001	0.95	1.88	
111	000	0.64	1.95	
111	111	0.33	2.02	
111	110	000	2.10	ADC mode default setting
110	001	-0.34	2.18	
110	000	-0.70	2.28	
110	111	-1.07	2.38	
110	110	-1.45	2.48	

Decimator Control Register

Address: 16h Attributes Write Only.

Register 17h reads back contents of register 16h.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	Reserved		EQON	DFS	MSB	TSEL[1:0]			
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:5	Reserved. Write as zero for future compatibility.
4	EQON: Equalizer Enable. This bit is used to enable or disable the digital equalizer. The equalizer can be switched on in order to reduce the group delay of the output data, at the cost of increased power.
	0 Equalizer disabled 1 Equalizer enabled
3	DFS: Data Format Select. Selects the format, either Offset Binary or Twos Complement of the output data
	0 2s Complement 1 Offset Binary
2	MSB: Select the bit order of the LVDS output data stream
	0 LSB first 1 MSB first
1:0	TSEL[1:0]: Training Sequence Select. These bits select the LVDS output data.
	The default mode of operation is where the filter output data is serialized.
	In the remaining modes the selected training sequence is repeatedly output from the serializer this allows the receiving data capture circuitry to perform the de-skewing process.
	One of three known words can be selected, the first two words are hard-coded in the block, the third one, the custom pattern, is written into User Registers 10h and 12h the Serializer Custom Pattern Registers .
	Note. The outputs bit-clock and word-clock are not affected by the value of the Training Sequence Select bits.
	00 ADC data[11:0]
	01 Training sequence 1: 0000001111111
	10 Training sequence 2: 101010101010
	11 Training sequence 3: custom pattern

LVDS Control Register

Address: 18h Attributes Write Only.

Register 19h reads back contents of register 18h.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description		Reserved		TX_term	I_driv	e[1:0]	ОСМ	SLVS	
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:5	Reserved. Write as zero for future compatibility.
4	TX_term: Enable Internal 100 Ohm termination for data outputs.
	0 Internal 100 ohm termination disabled
	1 Internal 100 ohm termination enabled
3:2	I_drive[1:0]: Controls the current drive of the data outputs.
	00 2.5 mA
	01 3.5 mA
	10 Reserved
	11 5 mA
1	OCM: Output Common mode. Allows the output common mode to be shifted depending on the setting of V _{DR} .
	If bit 0 of this register, SLVS, is set to 1 then changing OCM will have no impact on the output common
	mode. The output common mode in SLVS mode is fixed, as described in the Electrical Specifications section of this datasheet.
	For V _{DR} = 1.2V, OCM must be set to 0.
	For V _{DR} = 1.8V, OCM must be set to 1.
	0 Output Common Mode, V _{OCM} = 1.0V
	1 Output Common Mode, V _{OCM} = 1.25V
0	SLVS: Select the format for output data, either LVDS or SLVS. The differences in timing and electrical specifications between the two modes can be seen in the Electrical Specifications section of the datasheet.
	If this bit is set to 1 (SLVS mode), OCM has no effect and the output common mode will be set for SLVS as described in the Electrical Specifications section of this datasheet.
	When LVDS mode is selected, the output common mode must be selected using the OCM bit of this
	register.
	0 LVDS Mode
	1 SLVS Mode

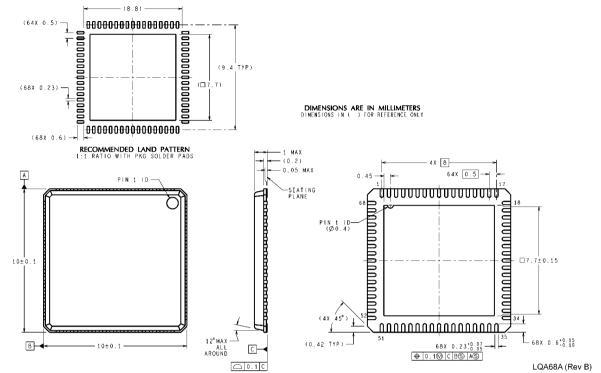
Chip ID Register

Address: 1Eh
Attributes Read Only.

	b[7]	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0]	HEX
Description	ID [7:0]								
Default	0	0	0	0	0	0	0	0	00 h

Bit	Description
7:0	ID[7:0]: Chip ID Register. Reading from this register will provide the chip version.
	The expected Chip ID for the ADC12EU050 is 12.4.
	X = ID[7]*8 + ID[6]*4 + ID[5]*2 + ID[4]
	Y = ID[3]*8 + ID[2]*4 + ID[1]*2 + ID[0]
	Chip ID = Version X.Y

Physical Dimensions inches (millimeters) unless otherwise noted



68-Lead LLP Package 10x10x1.0mm, 0.5mm Pitch Ordering Numbers ADC12EU050CIPLQ NS Package Number LQA68A

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